



Welcome to [E-XFL.COM](#)

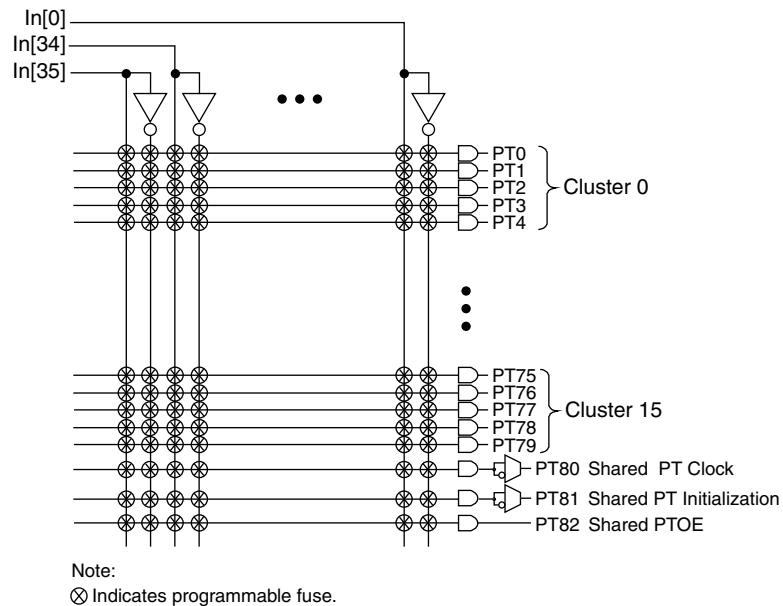
Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details

Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	7.5 ns
Voltage Supply - Internal	1.7V ~ 1.9V
Number of Logic Elements/Blocks	4
Number of Macrocells	64
Number of Gates	-
Number of I/O	64
Operating Temperature	0°C ~ 90°C (TJ)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-TQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lc4064zc-75t100c

Figure 3. AND Array

Enhanced Logic Allocator

Within the logic allocator, product terms are allocated to macrocells in product term clusters. Each product term cluster is associated with a macrocell. The cluster size for the ispMACH 4000 family is 4+1 (total 5) product terms. The software automatically considers the availability and distribution of product term clusters as it fits the functions within a GLB. The logic allocator is designed to provide three speed paths: 5-PT fast bypass path, 20-PT Speed Locking path and an up to 80-PT path. The availability of these three paths lets designers trade timing variability for increased performance.

The enhanced Logic Allocator of the ispMACH 4000 family consists of the following blocks:

- Product Term Allocator
- Cluster Allocator
- Wide Steering Logic

Figure 4 shows a macrocell slice of the Logic Allocator. There are 16 such slices in the GLB.

Figure 4. Macrocell Slice

Product Term Allocator

The product term allocator assigns product terms from a cluster to either logic or control applications as required by the design being implemented. Product terms that are used as logic are steered into a 5-input OR gate associated with the cluster. Product terms that are used for control are steered either to the macrocell or I/O cell associated with the cluster. Table 3 shows the available functions for each of the five product terms in the cluster. The OR gate output connects to the associated I/O cell, providing a fast path for narrow combinatorial functions, and to the logic allocator.

Table 3. Individual PT Steering

Product Term	Logic	Control
PT _n	Logic PT	Single PT for XOR/OR
PT _{n+1}	Logic PT	Individual Clock (PT Clock)
PT _{n+2}	Logic PT	Individual Initialization or Individual Clock Enable (PT Initialization/CE)
PT _{n+3}	Logic PT	Individual Initialization (PT Initialization)
PT _{n+4}	Logic PT	Individual OE (PTOE)

Cluster Allocator

The cluster allocator allows clusters to be steered to neighboring macrocells, thus allowing the creation of functions with more product terms. Table 4 shows which clusters can be steered to which macrocells. Used in this manner, the cluster allocator can be used to form functions of up to 20 product terms. Additionally, the cluster allocator accepts inputs from the wide steering logic. Using these inputs, functions up to 80 product terms can be created.

Table 4. Available Clusters for Each Macrocell

Macrocell	Available Clusters			
M0	—	C0	C1	C2
M1	C0	C1	C2	C3
M2	C1	C2	C3	C4
M3	C2	C3	C4	C5
M4	C3	C4	C5	C6
M5	C4	C5	C6	C7
M6	C5	C6	C7	C8
M7	C6	C7	C8	C9
M8	C7	C8	C9	C10
M9	C8	C9	C10	C11
M10	C9	C10	C11	C12
M11	C10	C11	C12	C13
M12	C11	C12	C13	C14
M13	C12	C13	C14	C15
M14	C13	C14	C15	—
M15	C14	C15	—	—

Wide Steering Logic

The wide steering logic allows the output of the cluster allocator n to be connected to the input of the cluster allocator $n+4$. Thus, cluster chains can be formed with up to 80 product terms, supporting wide product term functions and allowing performance to be increased through a single GLB implementation. Table 5 shows the product term chains.

Table 10. ORP Combinations for I/O Blocks with 12 I/Os

I/O Cell	Available Macrocells
I/O 0	M0, M1, M2, M3, M4, M5, M6, M7
I/O 1	M1, M2, M3, M4, M5, M6, M7, M8
I/O 2	M2, M3, M4, M5, M6, M7, M8, M9
I/O 3	M4, M5, M6, M7, M8, M9, M10, M11
I/O 4	M5, M6, M7, M8, M9, M10, M11, M12
I/O 5	M6, M7, M8, M9, M10, M11, M12, M13
I/O 6	M8, M9, M10, M11, M12, M13, M14, M15
I/O 7	M9, M10, M11, M12, M13, M14, M15, M0
I/O 8	M10, M11, M12, M13, M14, M15, M0, M1
I/O 9	M12, M13, M14, M15, M0, M1, M2, M3
I/O 10	M13, M14, M15, M0, M1, M2, M3, M4
I/O 11	M14, M15, M0, M1, M2, M3, M4, M5

ORP Bypass and Fast Output Multiplexers

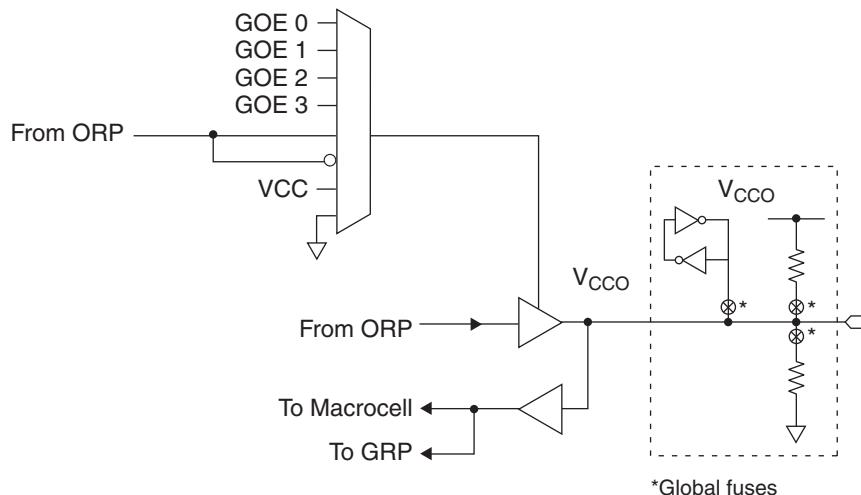
The ORP bypass and fast-path output multiplexer is a 4:1 multiplexer and allows the 5-PT fast path to bypass the ORP and be connected directly to the pin with either the regular output or the inverted output. This multiplexer also allows the register output to bypass the ORP to achieve faster t_{CO} .

Output Enable Routing Multiplexers

The OE Routing Pool provides the corresponding local output enable (OE) product term to the I/O cell.

I/O Cell

The I/O cell contains the following programmable elements: output buffer, input buffer, OE multiplexer and bus maintenance circuitry. Figure 8 details the I/O cell.

Figure 8. I/O Cell

Each output supports a variety of output standards dependent on the V_{CCO} supplied to its I/O bank. Outputs can also be configured for open drain operation. Each input can be programmed to support a variety of standards, independent of the V_{CCO} supplied to its I/O bank. The I/O standards supported are:

- LVTTL
- LVC MOS 1.8
- LVC MOS 3.3
- 3.3V PCI Compatible
- LVC MOS 2.5

All of the I/Os and dedicated inputs have the capability to provide a bus-keeper latch, Pull-up Resistor or Pull-down Resistor. A fourth option is to provide none of these. The selection is done on a global basis. The default in both hardware and software is such that when the device is erased or if the user does not specify, the input structure is configured to be a Pull-up Resistor.

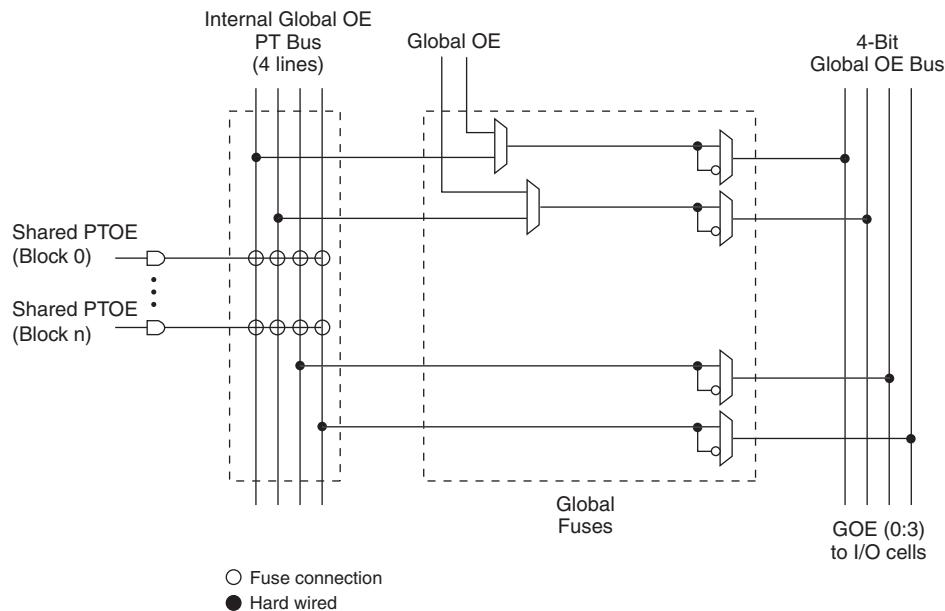
Each ispMACH 4000 device I/O has an individually programmable output slew rate control bit. Each output can be individually configured for fast slew or slow slew. The typical edge rate difference between fast and slow slew setting is 20%. For high-speed designs with long, unterminated traces, the slow-slew rate will introduce fewer reflections, less noise and keep ground bounce to a minimum. For designs with short traces or well terminated lines, the fast slew rate can be used to achieve the highest speed.

Global OE Generation

Most ispMACH 4000 family devices have a 4-bit wide Global OE Bus, except the ispMACH 4032 device that has a 2-bit wide Global OE Bus. This bus is derived from a 4-bit internal global OE PT bus and two dual purpose I/O or GOE pins. Each signal that drives the bus can optionally be inverted.

Each GLB has a block-level OE PT that connects to all bits of the Global OE PT bus with four fuses. Hence, for a 256-macrocell device (with 16 blocks), each line of the bus is driven from 16 OE product terms. Figures 9 and 10 show a graphical representation of the global OE generation.

Figure 9. Global OE Generation for All Devices Except ispMACH 4032



I/O Recommended Operating Conditions

Standard	V_{CCO} (V) ¹	
	Min.	Max.
LV TTL	3.0	3.6
LVC MOS 3.3	3.0	3.6
Extended LVC MOS 3.3 ²	2.7	3.6
LVC MOS 2.5	2.3	2.7
LVC MOS 1.8	1.65	1.95
PCI 3.3	3.0	3.6

1. Typical values for V_{CCO} are the average of the min. and max. values.

2. ispMACH 4000Z only.

DC Electrical Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
$I_{IL}, I_{IH}^{1,4}$	Input Leakage Current (ispMACH 4000Z)	$0 \leq V_{IN} < V_{CCO}$	—	0.5	1	μA
I_{IH}^1	Input High Leakage Current (ispMACH 4000Z)	$V_{CCO} < V_{IN} \leq 5.5V$	—	—	10	μA
I_{IL}, I_{IH}^1	Input Leakage Current (ispMACH 4000V/B/C)	$0 \leq V_{IN} \leq 3.6V, T_j = 105^\circ C$ $0 \leq V_{IN} \leq 3.6V, T_j = 130^\circ C$	—	—	10	μA
$I_{IH}^{1,2}$	Input High Leakage Current (ispMACH 4000V/B/C)	$3.6V < V_{IN} \leq 5.5V, T_j = 105^\circ C$ $3.0V \leq V_{CCO} \leq 3.6V$ $3.6V < V_{IN} \leq 5.5V, T_j = 130^\circ C$ $3.0V \leq V_{CCO} \leq 3.6V$	—	—	20	μA
I_{PU}	I/O Weak Pull-up Resistor Current (ispMACH 4000Z)	$0 \leq V_{IN} \leq 0.7V_{CCO}$	-30	—	-150	μA
I_{PU}	I/O Weak Pull-up Resistor Current (ispMACH 4000V/B/C)	$0 \leq V_{IN} \leq 0.7V_{CCO}$	-30	—	-200	μA
I_{PD}	I/O Weak Pull-down Resistor Current	$V_{IL} (\text{MAX}) \leq V_{IN} \leq V_{IH} (\text{MIN})$	30	—	150	μA
I_{BHLS}	Bus Hold Low Sustaining Current	$V_{IN} = V_{IL} (\text{MAX})$	30	—	—	μA
I_{BHHS}	Bus Hold High Sustaining Current	$V_{IN} = 0.7 V_{CCO}$	-30	—	—	μA
I_{BHLO}	Bus Hold Low Overdrive Current	$0V \leq V_{IN} \leq V_{BHT}$	—	—	150	μA
I_{BHHO}	Bus Hold High Overdrive Current	$V_{BHT} \leq V_{IN} \leq V_{CCO}$	—	—	-150	μA
V_{BHT}	Bus Hold Trip Points	—	$V_{CCO} * 0.35$	—	$V_{CCO} * 0.65$	V
C_1	I/O Capacitance ³	$V_{CCO} = 3.3V, 2.5V, 1.8V$ $V_{CC} = 1.8V, V_{IO} = 0$ to $V_{IH} (\text{MAX})$	—	8	—	pf
C_2	Clock Capacitance ³	$V_{CCO} = 3.3V, 2.5V, 1.8V$ $V_{CC} = 1.8V, V_{IO} = 0$ to $V_{IH} (\text{MAX})$	—	6	—	pf
C_3	Global Input Capacitance ³	$V_{CCO} = 3.3V, 2.5V, 1.8V$ $V_{CC} = 1.8V, V_{IO} = 0$ to $V_{IH} (\text{MAX})$	—	6	—	pf

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tristated. It is not measured with the output driver active. Bus maintenance circuits are disabled.

2. 5V tolerant inputs and I/O should only be placed in banks where $3.0V \leq V_{CCO} \leq 3.6V$.

3. $T_A = 25^\circ C, f = 1.0MHz$

4. I_{IH} excursions of up to $1.5\mu A$ maximum per pin above the spec limit may be observed for certain voltage conditions on no more than 10% of the device's I/O pins.

ispMACH 4000V/B/C External Switching Characteristics (Cont.)**Over Recommended Operating Conditions**

Parameter	Description ^{1, 2, 3}	-5		-75		-10		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{PD}	5-PT bypass combinatorial propagation delay	—	5.0	—	7.5	—	10.0	ns
t _{PD_MG}	20-PT combinatorial propagation delay through macrocell	—	5.5	—	8.0	—	10.5	ns
t _S	GLB register setup time before clock	3.0	—	4.5	—	5.5	—	ns
t _{ST}	GLB register setup time before clock with T-type register	3.2	—	4.7	—	5.5	—	ns
t _{SIR}	GLB register setup time before clock, input register path	1.2	—	1.7	—	1.7	—	ns
t _{SIRZ}	GLB register setup time before clock with zero hold	2.2	—	2.7	—	2.7	—	ns
t _H	GLB register hold time after clock	0.0	—	0.0	—	0.0	—	ns
t _{HT}	GLB register hold time after clock with T-type register	0.0	—	0.0	—	0.0	—	ns
t _{HIR}	GLB register hold time after clock, input register path	1.0	—	1.0	—	1.0	—	ns
t _{HIRZ}	GLB register hold time after clock, input register path with zero hold	0.0	—	0.0	—	0.0	—	ns
t _{CO}	GLB register clock-to-output delay	—	3.4	—	4.5	—	6.0	ns
t _R	External reset pin to output delay	—	6.3	—	9.0	—	10.5	ns
t _{RW}	External reset pulse duration	2.0	—	4.0	—	4.0	—	ns
t _{PTOE/DIS}	Input to output local product term output enable/disable	—	7.0	—	9.0	—	10.5	ns
t _{GPTOE/DIS}	Input to output global product term output enable/disable	—	9.0	—	10.3	—	12.0	ns
t _{GOE/DIS}	Global OE input to output enable/disable	—	5.0	—	7.0	—	8.0	ns
t _{CW}	Global clock width, high or low	2.2	—	2.8	—	4.0	—	ns
t _{GW}	Global gate width low (for low transparent) or high (for high transparent)	2.2	—	2.8	—	4.0	—	ns
t _{WIR}	Input register clock width, high or low	2.2	—	2.8	—	4.0	—	ns
f _{MAX} ⁴	Clock frequency with internal feedback	—	227	—	168	—	125	MHz
f _{MAX} (Ext.)	Clock frequency with external feedback, [1/ (t _S + t _{CO})]	—	156	—	111	—	86	MHz

1. Timing numbers are based on default LVC MOS 1.8 I/O buffers. Use timing adjusters provided to calculate other standards.

Timing v.3.2

2. Measured using standard switching circuit, assuming GRP loading of 1 and 1 output switching.

3. Pulse widths and clock widths less than minimum will cause unknown behavior.

4. Standard 16-bit counter using GRP feedback.

ispMACH 4000V/B/C Internal Timing Parameters

Over Recommended Operating Conditions

Parameter	Description	-2.5	-2.7	-3	-3.5	Units
In/Out Delays						
t_{IN}	Input Buffer Delay	—	0.60	—	0.60	—
t_{GOE}	Global OE Pin Delay	—	2.04	—	2.54	—
t_{GCLK_IN}	Global Clock Input Buffer Delay	—	0.78	—	1.28	—
t_{BUF}	Delay through Output Buffer	—	0.85	—	0.85	—
t_{EN}	Output Enable Time	—	0.96	—	0.96	—
t_{DIS}	Output Disable Time	—	0.96	—	0.96	—
Routing/GLB Delays						
t_{ROUTE}	Delay through GRP	—	0.61	—	0.81	—
t_{MCELL}	Macrocell Delay	—	0.45	—	0.55	—
t_{INREG}	Input Buffer to Macrocell Register Delay	—	0.11	—	0.31	—
t_{FBK}	Internal Feedback Delay	—	0.00	—	0.00	—
t_{PDb}	5-PT Bypass Propagation Delay	—	0.44	—	0.44	—
t_{PDi}	Macrocell Propagation Delay	—	0.64	—	0.64	—
Register/Latch Delays						
t_S	D-Register Setup Time (Global Clock)	0.92	—	1.12	—	1.02
t_{S_PT}	D-Register Setup Time (Product Term Clock)	1.42	—	1.32	—	1.32
t_{ST}	T-Register Setup Time (Global Clock)	1.12	—	1.32	—	1.22
t_{ST_PT}	T-Register Setup Time (Product Term Clock)	1.42	—	1.32	—	1.32
t_H	D-Register Hold Time	0.88	—	0.68	—	0.98
t_{HT}	T-Register Hold Time	0.88	—	0.68	—	0.98
t_{SIR}	D-Input Register Setup Time (Global Clock)	0.82	—	1.37	—	1.27
t_{SIR_PT}	D-Input Register Setup Time (Product Term Clock)	1.45	—	1.45	—	1.45
t_{HIR}	D-Input Register Hold Time (Global Clock)	0.88	—	0.63	—	0.73
t_{HIR_PT}	D-Input Register Hold Time (Product Term Clock)	0.88	—	0.63	—	0.73
t_{COi}	Register Clock to Output/Feedback MUX Time	—	0.52	—	0.52	—
t_{CES}	Clock Enable Setup Time	2.25	—	2.25	—	2.25
t_{CEH}	Clock Enable Hold Time	1.88	—	1.88	—	1.88
t_{SL}	Latch Setup Time (Global Clock)	0.92	—	1.12	—	1.02
t_{SL_PT}	Latch Setup Time (Product Term Clock)	1.42	—	1.32	—	1.32
t_{HL}	Latch Hold Time	1.17	—	1.17	—	1.17
t_{GOi}	Latch Gate to Output/Feedback MUX Time	—	0.33	—	0.33	—

ispMACH 4000V/B/C Internal Timing Parameters

Over Recommended Operating Conditions

Parameter	Description	-5		-75		-10		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
In/Out Delays								
t_{IN}	Input Buffer Delay	—	0.95	—	1.50	—	2.00	ns
t_{GOE}	Global OE Pin Delay	—	4.04	—	6.04	—	7.04	ns
t_{GCLK_IN}	Global Clock Input Buffer Delay	—	1.83	—	2.28	—	3.28	ns
t_{BUF}	Delay through Output Buffer	—	1.00	—	1.50	—	1.50	ns
t_{EN}	Output Enable Time	—	0.96	—	0.96	—	0.96	ns
t_{DIS}	Output Disable Time	—	0.96	—	0.96	—	0.96	ns
Routing/GLB Delays								
t_{ROUTE}	Delay through GRP	—	1.51	—	2.26	—	3.26	ns
t_{MCELL}	Macrocell Delay	—	1.05	—	1.45	—	1.95	ns
t_{INREG}	Input Buffer to Macrocell Register Delay	—	0.56	—	0.96	—	1.46	ns
t_{FBK}	Internal Feedback Delay	—	0.00	—	0.00	—	0.00	ns
t_{PD_b}	5-PT Bypass Propagation Delay	—	1.54	—	2.24	—	3.24	ns
t_{PD_i}	Macrocell Propagation Delay	—	0.94	—	1.24	—	1.74	ns
Register/Latch Delays								
t_S	D-Register Setup Time (Global Clock)	1.32	—	1.57	—	1.57	—	ns
t_{S_PT}	D-Register Setup Time (Product Term Clock)	1.32	—	1.32	—	1.32	—	ns
t_{ST}	T-Register Setup Time (Global Clock)	1.52	—	1.77	—	1.77	—	ns
t_{ST_PT}	T-Register Setup Time (Product Term Clock)	1.32	—	1.32	—	1.32	—	ns
t_H	D-Register Hold Time	1.68	—	2.93	—	3.93	—	ns
t_{HT}	T-Register Hold Time	1.68	—	2.93	—	3.93	—	ns
t_{SIR}	D-Input Register Setup Time (Global Clock)	1.52	—	1.57	—	1.57	—	ns
t_{SIR_PT}	D-Input Register Setup Time (Product Term Clock)	1.45	—	1.45	—	1.45	—	ns
t_{HIR}	D-Input Register Hold Time (Global Clock)	0.68	—	1.18	—	1.18	—	ns
t_{HIR_PT}	D-Input Register Hold Time (Product Term Clock)	0.68	—	1.18	—	1.18	—	ns
t_{COi}	Register Clock to Output/Feedback MUX Time	—	0.52	—	0.67	—	1.17	ns
t_{CES}	Clock Enable Setup Time	2.25	—	2.25	—	2.25	—	ns
t_{CEH}	Clock Enable Hold Time	1.88	—	1.88	—	1.88	—	ns
t_{SL}	Latch Setup Time (Global Clock)	1.32	—	1.57	—	1.57	—	ns
t_{SL_PT}	Latch Setup Time (Product Term Clock)	1.32	—	1.32	—	1.32	—	ns
t_{HL}	Latch Hold Time	1.17	—	1.17	—	1.17	—	ns
t_{GOi}	Latch Gate to Output/Feedback MUX Time	—	0.33	—	0.33	—	0.33	ns
t_{PDLi}	Propagation Delay through Transparent Latch to Output/Feedback MUX	—	0.25	—	0.25	—	0.25	ns
t_{SRi}	Asynchronous Reset or Set to Output/Feedback MUX Delay	0.28	—	0.28	—	0.28	—	ns
t_{SRR}	Asynchronous Reset or Set Recovery Time	1.67	—	1.67	—	1.67	—	ns
Control Delays								
t_{BCLK}	GLB PT Clock Delay	—	1.12	—	1.12	—	0.62	ns
t_{PTCLK}	Macrocell PT Clock Delay	—	0.87	—	0.87	—	0.87	ns
t_{BSR}	GLB PT Set/Reset Delay	—	1.83	—	1.83	—	1.83	ns
t_{PTSR}	Macrocell PT Set/Reset Delay	—	2.51	—	3.41	—	3.41	ns

ispMACH 4000Z Internal Timing Parameters (Cont.)

Over Recommended Operating Conditions

Parameter	Description	-45		-5		-75		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{PTOE}	Macrocell PT OE Delay	—	2.50	—	2.70	—	2.00	ns

Note: Internal Timing Parameters are not tested and are for reference only. Refer to the timing model in this data sheet for further details.

Timing v.2.2

ispMACH 4000Z Timing Adders (Cont.)¹

Adder Type	Base Parameter	Description	-45		-5		-75		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
Optional Delay Adders									
t _{INDIO}	t _{INREG}	Input register delay	—	1.30	—	1.30	—	1.30	ns
t _{EXP}	t _{MCELL}	Product term expander delay	—	0.45	—	0.45	—	0.50	ns
t _{ORP}	—	Output routing pool delay	—	0.40	—	0.40	—	0.40	ns
t _{BLA}	t _{ROUTE}	Additional block loading adder	—	0.05	—	0.05	—	0.05	ns
t_{IOL} Input Adjusters									
LVTTL_in	t _{IN} , t _{GCLK_IN} , t _{GOE}	Using LVTTL standard	—	0.60	—	0.60	—	0.60	ns
LVCMOS33_in	t _{IN} , t _{GCLK_IN} , t _{GOE}	Using LVCMOS 3.3 standard	—	0.60	—	0.60	—	0.60	ns
LVCMOS25_in	t _{IN} , t _{GCLK_IN} , t _{GOE}	Using LVCMOS 2.5 standard	—	0.60	—	0.60	—	0.60	ns
LVCMOS18_in	t _{IN} , t _{GCLK_IN} , t _{GOE}	Using LVCMOS 1.8 standard	—	0.00	—	0.00	—	0.00	ns
PCI_in	t _{IN} , t _{GCLK_IN} , t _{GOE}	Using PCI compatible input	—	0.60	—	0.60	—	0.60	ns
t_{IOO} Output Adjusters									
LVTTL_out	t _{BUF} , t _{EN} , t _{DIS}	Output configured as TTL buffer	—	0.20	—	0.20	—	0.20	ns
LVCMOS33_out	t _{BUF} , t _{EN} , t _{DIS}	Output configured as 3.3V buffer	—	0.20	—	0.20	—	0.20	ns
LVCMOS25_out	t _{BUF} , t _{EN} , t _{DIS}	Output configured as 2.5V buffer	—	0.10	—	0.10	—	0.10	ns
LVCMOS18_out	t _{BUF} , t _{EN} , t _{DIS}	Output configured as 1.8V buffer	—	0.00	—	0.00	—	0.00	ns
PCI_out	t _{BUF} , t _{EN} , t _{DIS}	Output configured as PCI compatible buffer	—	0.20	—	0.20	—	0.20	ns
Slow Slew	t _{BUF} , t _{EN}	Output configured for slow slew rate	—	1.00	—	1.00	—	1.00	ns

Note: Open drain timing is the same as corresponding LVCMOS timing.

Timing v.2.2

1. Refer to TN1004, [ispMACH 4000 Timing Model Design and Usage Guidelines](#) for information regarding use of these adders.

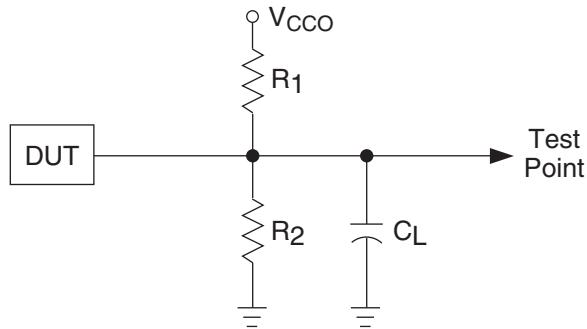
Boundary Scan Waveforms and Timing Specifications

Symbol	Parameter	Min.	Max.	Units
t_{BTCP}	TCK [BSCAN test] clock cycle	40	—	ns
t_{BTCH}	TCK [BSCAN test] pulse width high	20	—	ns
t_{BTCL}	TCK [BSCAN test] pulse width low	20	—	ns
t_{BTSU}	TCK [BSCAN test] setup time	8	—	ns
t_{BTH}	TCK [BSCAN test] hold time	10	—	ns
t_{BRF}	TCK [BSCAN test] rise and fall time	50	—	mV/ns
t_{BTCO}	TAP controller falling edge of clock to valid output	—	10	ns
t_{BTOZ}	TAP controller falling edge of clock to data output disable	—	10	ns
t_{BTVO}	TAP controller falling edge of clock to data output enable	—	10	ns
t_{BTCPSU}	BSCAN test Capture register setup time	8	—	ns
t_{TCPH}	BSCAN test Capture register hold time	10	—	ns
t_{BTUCO}	BSCAN test Update reg, falling edge of clock to valid output	—	25	ns
t_{BTUOZ}	BSCAN test Update reg, falling edge of clock to output disable	—	25	ns
t_{BTUOV}	BSCAN test Update reg, falling edge of clock to output enable	—	25	ns

Switching Test Conditions

Figure 12 shows the output test load that is used for AC testing. The specific values for resistance, capacitance, voltage, and other test conditions are shown in Table 11.

Figure 12. Output Test Load, LVTTL and LVC MOS Standards



0213A/ispm4k

Table 11. Test Fixture Required Components

Test Condition	R ₁	R ₂	C _L ¹	Timing Ref.	V _{CCO}
LVC MOS I/O, (L → H, H → L)	106Ω	106Ω	35pF	LVC MOS 3.3 = 1.5V	LVC MOS 3.3 = 3.0V
				LVC MOS 2.5 = V _{CCO} /2	LVC MOS 2.5 = 2.3V
				LVC MOS 1.8 = V _{CCO} /2	LVC MOS 1.8 = 1.65V
LVC MOS I/O (Z → H)	∞	106Ω	35pF	1.5V	3.0V
LVC MOS I/O (Z → L)	106Ω	∞	35pF	1.5V	3.0V
LVC MOS I/O (H → Z)	∞	106Ω	5pF	V _{OH} - 0.3	3.0V
LVC MOS I/O (L → Z)	106Ω	∞	5pF	V _{OL} + 0.3	3.0V

1. C_L includes test fixtures and probe capacitance.

Signal Descriptions

Signal Names		Description
TMS		Input – This pin is the IEEE 1149.1 Test Mode Select input, which is used to control the state machine.
TCK		Input – This pin is the IEEE 1149.1 Test Clock input pin, used to clock through the state machine.
TDI		Input – This pin is the IEEE 1149.1 Test Data In pin, used to load data.
TDO		Output – This pin is the IEEE 1149.1 Test Data Out pin used to shift data out.
GOE0/IO, GOE1/IO		These pins are configured to be either Global Output Enable Input or as general I/O pins.
GND		Ground
NC		Not Connected
V _{CC}		The power supply pins for logic core and JTAG port.
CLK0/I, CLK1/I, CLK2/I, CLK3/I		These pins are configured to be either CLK input or as an input.
V _{CC00} , V _{CC01}		The power supply pins for each I/O bank.
yzz		Input/Output ¹ – These are the general purpose I/O used by the logic array. y is GLB reference (alpha) and z is macrocell reference (numeric). z: 0-15.
		ispMACH 4032
		ispMACH 4064
		ispMACH 4128
		ispMACH 4256
		ispMACH 4384
		ispMACH 4512
		y: A-B
		y: A-D
		y: A-H
		y: A-P
		y: A-P, AX-HX
		y: A-P, AX-PX

1. In some packages, certain I/Os are only available for use as inputs. See the signal connections table for details.

ispMACH 4000V/B/C ORP Reference Table

	4032V/B/C		4064V/B/C			4128V/B/C			4256V/B/C				4384V/B/C		4512V/B/C	
Number of I/Os	30 ¹	32	30 ²	32	64	64	92 ³	96	64	96 ⁴	128	160	128	192	128	208
Number of GLBs	2	2	4	4	4	8	8	8	16	16	16	16	16	16	16	16
Number of I/Os / GLB	16	16	8	8	16	8	12	12	4	8	8	10	8	8	8	Mixture of 8 & 4 ⁵
Reference ORP Table	16 I/Os / GLB		8 I/Os / GLB		16 I/Os / GLB		8 I/Os / GLB		12 I/Os / GLB		4 I/Os / GLB		8 I/Os / GLB		10 I/Os / GLB	
															8 I/Os / GLB	
															4 I/Os / GLB	

1. 32-macrocell device, 44 TQFP: 2 GLBs have 15 out of 16 I/Os bonded out.

2. 64-macrocell device, 44 TQFP: 2 GLBs have 7 out of 8 I/Os bonded out.

3. 128-macrocell device, 128 TQFP: 4 GLBs have 11 out of 12 I/Os

4. 256-macrocell device, 144 TQFP: 16 GLBs have 6 I/Os per

5. 512-macrocell device: 20 GLBs have 8 I/Os per, 12 GLBs have 4 I/Os per

ispMACH 4000Z ORP Reference Table

	4032Z		4064Z			4128Z			4256Z			
Number of I/Os	32	32	64			64	96	64	96 ¹	128		
Number of GLBs	2	4	4			8	8	16	16	16		
Number of I/Os / GLB	16	8	16			8	12	4	8	8		
Reference ORP Table	16 I/Os / GLB		8 I/Os / GLB		16 I/Os / GLB		8 I/Os / GLB		12 I/Os / GLB		4 I/Os / GLB	

1. 256-macrocell device, 132 csBGA: 16 GLBs have 6 I/Os per

ispMACH 4000V/B/C/Z Power Supply and NC Connections¹ (Cont.)

Signal	132-ball csBGA ⁷	144-pin TQFP ⁴	176-pin TQFP ⁴	256-ball ftBGA/fpBGA ^{2, 3, 7, 9}
VCC	P1, A14, B7, N8	36, 57, 108, 129	42, 69, 88, 130, 157, 176	B2, B15, G8, G9, K8, K9, R2, R15
VCCO0 VCCO (Bank 0)	G3, P5, C1 ⁸ , M2 ⁸ , C5	3, 19, 34, 47, 136	4, 22, 40, 56, 166	D6, F4, H7, J7, L4, N6
VCCO1 VCCO (Bank 1)	M10, M14 ⁸ , H12, A10, C13 ⁸	64, 75, 91, 106, 119	78, 92, 110, 128, 144	D11, F13, H10, J10, L13, N11
GND	B1, P2, N14, A13	1, 37, 73, 109	2, 46 ⁵ , 65, 90, 134, 153	A1, A16, C6, C11, F3, F14, G7, G10, H8, H9, J8, J9, K7, K10, L3, L14, P6, P11, T1, T16
GND (Bank 0)	E2, K2, N4, B4	10, 18 ⁶ , 27, 46, 127, 137	13, 31, 55, 155, 167	
GND (Bank 1)	N11, K13, E13, B11	55, 65, 82, 90 ⁶ , 99, 118	67, 79, 101, 119, 143	
NC	4064Z: C1, C3, E1, E3, H2, J3, K1, M2, M4, N5, P7, P8, M8, P10, P11, P14, M12, K14, K12, G13, G14, E14, C13, B13, B10, C10, A7, B5, A5, A4, A1 4128Z: P8, A7	4128V: 17, 20, 38, 45, 72, 89, 92, 110, 117, 144 4256V: 18, 90	1, 43, 44, 45, 89, 131, 132, 133	4256V/B/C, 128 I/O: A4, A5, A6, A11, A12, A13, A15, B5, B6, B11, B12, B14, C7, D1, D4, D5, D10, D12, D16, E1, E2, E4, E5, E7, E10, E13, E14, E15, E16, F1, F2, F15, F16, G1, G4, G5, G6, G12, G13, G14, J11, K3, K4, K15, L1, L2, L12, L15, L16, M1, M2, M3, M4, M5, M12, M13, M15, M16, N1, N2, N7, N10, N12, N14, P5, P12, R4, R5, R6, R11, R12, R16, T2, T4, T5, T6, T11, T12, T13, T15 4256V/B/C, 160 I/O: A5, A12, A15, B5, B6, B11, B12, B14, D4, D5, D12, E1, E4, E5, E13, E15, E16, F1, F2, F15, G1, G5, G12, G14, L1, L2, L12, L15, L16, M1, M2, M3, M12, M16, N1, N12, N14, P5, P12, R4, R5, R6, R11, R12, R16, T4, T5, T12, T15 4384V/B/C: B5, B12, D5, D12, E1, E15, E16, F2, L12, M1, M2, M16, N12, R5, R12, T4 4512V/B/C: None

1. All grounds must be electrically connected at the board level. However, for the purposes of I/O current loading, grounds are associated with the bank shown.
2. Internal GNDs and I/O GNDs (Bank 0/1) are connected inside package.
3. V_{CCO} balls connect to two power planes within the package, one for V_{CCO0} and one for V_{CCO1}.
4. Pin orientation follows the conventional order from pin 1 marking of the top side view and counter-clockwise.
5. ispMACH 4384V/B/C pin 46 is tied to GND (Bank 0).
6. ispMACH 4128V only.
7. Pin orientation A1 starts from the upper left corner of the top side view with alphabetical order ascending vertically and numerical order ascending horizontally.
8. ispMACH 4128Z and 4256Z only. NC for ispMACH 4064Z.
9. Use 256 ftBGA package for all new designs. Refer to PCN#14A-07 for 256 fpBGA package discontinuance.

ispMACH 4000C (1.8V) Commercial Devices (Cont.)

Device	Part Number	Macrocells	Voltage	t _{PD}	Package	Pin/Ball Count	I/O	Grade
LC4128C	LC4128C-27T128C	128	1.8	2.7	TQFP	128	92	C
	LC4128C-5T128C	128	1.8	5	TQFP	128	92	C
	LC4128C-75T128C	128	1.8	7.5	TQFP	128	92	C
	LC4128C-27T100C	128	1.8	2.7	TQFP	100	64	C
	LC4128C-5T100C	128	1.8	5	TQFP	100	64	C
	LC4128C-75T100C	128	1.8	7.5	TQFP	100	64	C
LC4256C	LC4256C-3FT256AC	256	1.8	3	ftBGA	256	128	C
	LC4256C-5FT256AC	256	1.8	5	ftBGA	256	128	C
	LC4256C-75FT256AC	256	1.8	7.5	ftBGA	256	128	C
	LC4256C-3FT256BC	256	1.8	3	ftBGA	256	160	C
	LC4256C-5FT256BC	256	1.8	5	ftBGA	256	160	C
	LC4256C-75FT256BC	256	1.8	7.5	ftBGA	256	160	C
	LC4256C-3F256AC ¹	256	1.8	3	fpBGA	256	128	C
	LC4256C-5F256AC ¹	256	1.8	5	fpBGA	256	128	C
	LC4256C-75F256AC ¹	256	1.8	7.5	fpBGA	256	128	C
	LC4256C-3F256BC ¹	256	1.8	3	fpBGA	256	160	C
	LC4256C-5F256BC ¹	256	1.8	5	fpBGA	256	160	C
	LC4256C-75F256BC ¹	256	1.8	7.5	fpBGA	256	160	C
	LC4256C-3T176C	256	1.8	3	TQFP	176	128	C
	LC4256C-5T176C	256	1.8	5	TQFP	176	128	C
	LC4256C-75T176C	256	1.8	7.5	TQFP	176	128	C
	LC4256C-3T100C	256	1.8	3	TQFP	100	64	C
	LC4256C-5T100C	256	1.8	5	TQFP	100	64	C
	LC4256C-75T100C	256	1.8	7.5	TQFP	100	64	C
LC4384C	LC4384C-35FT256C	384	1.8	3.5	ftBGA	256	192	C
	LC4384C-5FT256C	384	1.8	5	ftBGA	256	192	C
	LC4384C-75FT256C	384	1.8	7.5	ftBGA	256	192	C
	LC4384C-35F256C ¹	384	1.8	3.5	fpBGA	256	192	C
	LC4384C-5F256C ¹	384	1.8	5	fpBGA	256	192	C
	LC4384C-75F256C ¹	384	1.8	7.5	fpBGA	256	192	C
	LC4384C-35T176C	384	1.8	3.5	TQFP	176	128	C
	LC4384C-5T176C	384	1.8	5	TQFP	176	128	C
	LC4384C-75T176C	384	1.8	7.5	TQFP	176	128	C
LC4512C	LC4512C-35FT256C	512	1.8	3.5	ftBGA	256	208	C
	LC4512C-5FT256C	512	1.8	5	ftBGA	256	208	C
	LC4512C-75FT256C	512	1.8	7.5	ftBGA	256	208	C
	LC4512C-35F256C ¹	512	1.8	3.5	fpBGA	256	208	C
	LC4512C-5F256C ¹	512	1.8	5	fpBGA	256	208	C
	LC4512C-75F256C ¹	512	1.8	7.5	fpBGA	256	208	C
	LC4512C-35T176C	512	1.8	3.5	TQFP	176	128	C
	LC4512C-5T176C	512	1.8	5	TQFP	176	128	C
	LC4512C-75T176C	512	1.8	7.5	TQFP	176	128	C

1. Use ftBGA package. fpBGA package devices have been discontinued via PCN#14A-07.

ispMACH 4000V (3.3V) Commercial Devices (Cont.)

Device	Part Number	Macrocells	Voltage	t _{PD}	Package	Pin/Ball Count	I/O	Grade
LC4128V	LC4128V-27T144C	128	3.3	2.7	TQFP	144	96	C
	LC4128V-5T144C	128	3.3	5	TQFP	144	96	C
	LC4128V-75T144C	128	3.3	7.5	TQFP	144	96	C
	LC4128V-27T128C	128	3.3	2.7	TQFP	128	92	C
	LC4128V-5T128C	128	3.3	5	TQFP	128	92	C
	LC4128V-75T128C	128	3.3	7.5	TQFP	128	92	C
	LC4128V-27T100C	128	3.3	2.7	TQFP	100	64	C
	LC4128V-5T100C	128	3.3	5	TQFP	100	64	C
	LC4128V-75T100C	128	3.3	7.5	TQFP	100	64	C
LC4256V	LC4256V-3FT256AC	256	3.3	3	ftBGA	256	128	C
	LC4256V-5FT256AC	256	3.3	5	ftBGA	256	128	C
	LC4256V-75FT256AC	256	3.3	7.5	ftBGA	256	128	C
	LC4256V-3FT256BC	256	3.3	3	ftBGA	256	160	C
	LC4256V-5FT256BC	256	3.3	5	ftBGA	256	160	C
	LC4256V-75FT256BC	256	3.3	7.5	ftBGA	256	160	C
	LC4256V-3F256AC ¹	256	3.3	3	fpBGA	256	128	C
	LC4256V-5F256AC ¹	256	3.3	5	fpBGA	256	128	C
	LC4256V-75F256AC ¹	256	3.3	7.5	fpBGA	256	128	C
	LC4256V-3F256BC ¹	256	3.3	3	fpBGA	256	160	C
	LC4256V-5F256BC ¹	256	3.3	5	fpBGA	256	160	C
	LC4256V-75F256BC ¹	256	3.3	7.5	fpBGA	256	160	C
	LC4256V-3T176C	256	3.3	3	TQFP	176	128	C
	LC4256V-5T176C	256	3.3	5	TQFP	176	128	C
	LC4256V-75T176C	256	3.3	7.5	TQFP	176	128	C
	LC4256V-3T144C	256	3.3	3	TQFP	144	96	C
	LC4256V-5T144C	256	3.3	5	TQFP	144	96	C
	LC4256V-75T144C	256	3.3	7.5	TQFP	144	96	C
	LC4256V-3T100C	256	3.3	3	TQFP	100	64	C
	LC4256V-5T100C	256	3.3	5	TQFP	100	64	C
	LC4256V-75T100C	256	3.3	7.5	TQFP	100	64	C
LC4384V	LC4384V-35FT256C	384	3.3	3.5	ftBGA	256	192	C
	LC4384V-5FT256C	384	3.3	5	ftBGA	256	192	C
	LC4384V-75FT256C	384	3.3	7.5	ftBGA	256	192	C
	LC4384V-35F256C ¹	384	3.3	3.5	fpBGA	256	192	C
	LC4384V-5F256C ¹	384	3.3	5	fpBGA	256	192	C
	LC4384V-75F256C ¹	384	3.3	7.5	fpBGA	256	192	C
	LC4384V-35T176C	384	3.3	3.5	TQFP	176	128	C
	LC4384V-5T176C	384	3.3	5	TQFP	176	128	C
	LC4384V-75T176C	384	3.3	7.5	TQFP	176	128	C

ispMACH 4000Z (Zero Power, 1.8V) Lead-Free Industrial Devices (Cont.)

Device	Part Number	Macrocells	Voltage	t _{PD}	Package	Pin/Ball Count	I/O	Grade
LC4064ZC	LC4064ZC-5MN132I	64	1.8	5	Lead-free csBGA	132	64	I
	LC4064ZC-75MN132I	64	1.8	7.5	Lead-free csBGA	132	64	I
	LC4064ZC-5TN100I	64	1.8	5	Lead-free TQFP	100	64	I
	LC4064ZC-75TN100I	64	1.8	7.5	Lead-free TQFP	100	64	I
	LC4064ZC-5MN56I	64	1.8	5	Lead-free csBGA	56	32	I
	LC4064ZC-75MN56I	64	1.8	7.5	Lead-free csBGA	56	32	I
	LC4064ZC-5TN48I	64	1.8	5	Lead-free TQFP	48	32	I
	LC4064ZC-75TN48I	64	1.8	7.5	Lead-free TQFP	48	32	I
LC4128ZC	LC4128ZC-75MN132I	128	1.8	7.5	Lead-free csBGA	132	96	I
	LC4128ZC-75TN100I	128	1.8	7.5	Lead-free TQFP	100	64	I
LC4256ZC	LC4256ZC-75TN176I	256	1.8	7.5	Lead-free TQFP	176	128	I
	LC4256ZC-75MN132I	256	1.8	7.5	Lead-free csBGA	132	96	I
	LC4256ZC-75TN100I	256	1.8	7.5	Lead-free TQFP	100	64	I

ispMACH 4000Z (Zero Power, 1.8V) Lead-Free Extended Temperature Devices

Device	Part Number	Macrocells	Voltage	t _{PD}	Package	Pin/Ball Count	I/O	Grade
LC4032ZC	LC4032ZC-75TN48E	32	1.8	7.5	Lead-free TQFP	48	32	E
LC4064ZC	LC4064ZC-75TN100E	64	1.8	7.5	Lead-free TQFP	100	64	E
	LC4064ZC-75TN48E	64	1.8	7.5	Lead-free TQFP	48	32	E
LC4128ZC	LC4128ZC-75TN100E	128	1.8	7.5	Lead-free TQFP	100	64	E
LC4256ZC	LC4256ZC-75TN176E	256	1.8	7.5	Lead-free TQFP	176	128	E
	LC4256ZC-75TN100E	256	1.8	7.5	Lead-free TQFP	100	64	E

ispMACH 4000C (1.8V) Lead-Free Commercial Devices

Device	Part Number	Macrocells	Voltage	t _{PD}	Package	Pin/Ball Count	I/O	Grade
LC4032C	LC4032C-25TN48C	32	1.8	2.5	Lead-free TQFP	48	32	C
	LC4032C-5TN48C	32	1.8	5	Lead-free TQFP	48	32	C
	LC4032C-75TN48C	32	1.8	7.5	Lead-free TQFP	48	32	C
	LC4032C-25TN44C	32	1.8	2.5	Lead-free TQFP	44	30	C
	LC4032C-5TN44C	32	1.8	5	Lead-free TQFP	44	30	C
	LC4032C-75TN44C	32	1.8	7.5	Lead-free TQFP	44	30	C

ispMACH 4000C (1.8V) Lead-Free Commercial Devices (Cont.)

Device	Part Number	Macrocells	Voltage	t _{PD}	Package	Pin/Ball Count	I/O	Grade
LC4064C	LC4064C-25TN100C	64	1.8	2.5	Lead-free TQFP	100	64	C
	LC4064C-5TN100C	64	1.8	5	Lead-free TQFP	100	64	C
	LC4064C-75TN100C	64	1.8	7.5	Lead-free TQFP	100	64	C
	LC4064C-25TN48C	64	1.8	2.5	Lead-free TQFP	48	32	C
	LC4064C-5TN48C	64	1.8	5	Lead-free TQFP	48	32	C
	LC4064C-75TN48C	64	1.8	7.5	Lead-free TQFP	48	32	C
	LC4064C-25TN44C	64	1.8	2.5	Lead-free TQFP	44	30	C
	LC4064C-5TN44C	64	1.8	5	Lead-free TQFP	44	30	C
	LC4064C-75TN44C	64	1.8	7.5	Lead-free TQFP	44	30	C
LC4128C	LC4128C-27TN128C	128	1.8	2.7	Lead-free TQFP	128	92	C
	LC4128C-5TN128C	128	1.8	5	Lead-free TQFP	128	92	C
	LC4128C-75TN128C	128	1.8	7.5	Lead-free TQFP	128	92	C
	LC4128C-27TN100C	128	1.8	2.7	Lead-free TQFP	100	64	C
	LC4128C-5TN100C	128	1.8	5	Lead-free TQFP	100	64	C
	LC4128C-75TN100C	128	1.8	7.5	Lead-free TQFP	100	64	C
LC4256C	LC4256C-3FTN256AC	256	1.8	3	Lead-free ftBGA	256	128	C
	LC4256C-5FTN256AC	256	1.8	5	Lead-free ftBGA	256	128	C
	LC4256C-75FTN256AC	256	1.8	7.5	Lead-free ftBGA	256	128	C
	LC4256C-3FTN256BC	256	1.8	3	Lead-free ftBGA	256	160	C
	LC4256C-5FTN256BC	256	1.8	5	Lead-free ftBGA	256	160	C
	LC4256C-75FTN256BC	256	1.8	7.5	Lead-free ftBGA	256	160	C
	LC4256C-3FN256AC ¹	256	1.8	3	Lead-free fpBGA	256	128	C
	LC4256C-5FN256AC ¹	256	1.8	5	Lead-free fpBGA	256	128	C
	LC4256C-75FN256AC ¹	256	1.8	7.5	Lead-free fpBGA	256	128	C
	LC4256C-3FN256BC ¹	256	1.8	3	Lead-free fpBGA	256	160	C
	LC4256C-5FN256BC ¹	256	1.8	5	Lead-free fpBGA	256	160	C
	LC4256C-75FN256BC ¹	256	1.8	7.5	Lead-free fpBGA	256	160	C
	LC4256C-3TN176C	256	1.8	3	Lead-free TQFP	176	128	C
	LC4256C-5TN176C	256	1.8	5	Lead-free TQFP	176	128	C
	LC4256C-75TN176C	256	1.8	7.5	Lead-free TQFP	176	128	C
	LC4256C-3TN100C	256	1.8	3	Lead-free TQFP	100	64	C
	LC4256C-5TN100C	256	1.8	5	Lead-free TQFP	100	64	C
	LC4256C-75TN100C	256	1.8	7.5	Lead-free TQFP	100	64	C
LC4384C	LC4384C-35FTN256C	384	1.8	3.5	Lead-free ftBGA	256	192	C
	LC4384C-5FTN256C	384	1.8	5	Lead-free ftBGA	256	192	C
	LC4384C-75FTN256C	384	1.8	7.5	Lead-free ftBGA	256	192	C
	LC4384C-35FN256C ¹	384	1.8	3.5	Lead-free fpBGA	256	192	C
	LC4384C-5FN256C ¹	384	1.8	5	Lead-free fpBGA	256	192	C
	LC4384C-75FN256C ¹	384	1.8	7.5	Lead-free fpBGA	256	192	C
	LC4384C-35TN176C	384	1.8	3.5	Lead-free TQFP	176	128	C
	LC4384C-5TN176C	384	1.8	5	Lead-free TQFP	176	128	C
	LC4384C-75TN176C	384	1.8	7.5	Lead-free TQFP	176	128	C

ispMACH 4000V (3.3V) Lead-Free Commercial Devices (Cont.)

Device	Part Number	Macrocells	Voltage	t _{PD}	Package	Pin/Ball Count	I/O	Grade
LC4256V	LC4256V-3FTN256AC	256	3.3	3	Lead-free ftBGA	256	128	C
	LC4256V-5FTN256AC	256	3.3	5	Lead-free ftBGA	256	128	C
	LC4256V-75FTN256AC	256	3.3	7.5	Lead-free ftBGA	256	128	C
	LC4256V-3FTN256BC	256	3.3	3	Lead-free ftBGA	256	160	C
	LC4256V-5FTN256BC	256	3.3	5	Lead-free ftBGA	256	160	C
	LC4256V-75FTN256BC	256	3.3	7.5	Lead-free ftBGA	256	160	C
	LC4256V-3FN256AC ¹	256	3.3	3	Lead-free fpBGA	256	128	C
	LC4256V-5FN256AC ¹	256	3.3	5	Lead-free fpBGA	256	128	C
	LC4256V-75FN256AC ¹	256	3.3	7.5	Lead-free fpBGA	256	128	C
	LC4256V-3FN256BC ¹	256	3.3	3	Lead-free fpBGA	256	160	C
	LC4256V-5FN256BC ¹	256	3.3	5	Lead-free fpBGA	256	160	C
	LC4256V-75FN256BC ¹	256	3.3	7.5	Lead-free fpBGA	256	160	C
	LC4256V-3TN176C	256	3.3	3	Lead-free TQFP	176	128	C
	LC4256V-5TN176C	256	3.3	5	Lead-free TQFP	176	128	C
	LC4256V-75TN176C	256	3.3	7.5	Lead-free TQFP	176	128	C
	LC4256V-3TN144C	256	3.3	3	Lead-free TQFP	144	96	C
	LC4256V-5TN144C	256	3.3	5	Lead-free TQFP	144	96	C
	LC4256V-75TN144C	256	3.3	7.5	Lead-free TQFP	144	96	C
	LC4256V-3TN100C	256	3.3	3	Lead-free TQFP	100	64	C
	LC4256V-5TN100C	256	3.3	5	Lead-free TQFP	100	64	C
	LC4256V-75TN100C	256	3.3	7.5	Lead-free TQFP	100	64	C
LC4384V	LC4384V-35FTN256C	384	3.3	3.5	Lead-free ftBGA	256	192	C
	LC4384V-5FTN256C	384	3.3	5	Lead-free ftBGA	256	192	C
	LC4384V-75FTN256C	384	3.3	7.5	Lead-free ftBGA	256	192	C
	LC4384V-35FN256C ¹	384	3.3	3.5	Lead-free fpBGA	256	192	C
	LC4384V-5FN256C ¹	384	3.3	5	Lead-free fpBGA	256	192	C
	LC4384V-75FN256C ¹	384	3.3	7.5	Lead-free fpBGA	256	192	C
	LC4384V-35TN176C	384	3.3	3.5	Lead-free TQFP	176	128	C
	LC4384V-5TN176C	384	3.3	5	Lead-free TQFP	176	128	C
	LC4384V-75TN176C	384	3.3	7.5	Lead-free TQFP	176	128	C
LC4512V	LC4512V-35FTN256C	512	3.3	3.5	Lead-free ftBGA	256	208	C
	LC4512V-5FTN256C	512	3.3	5	Lead-free ftBGA	256	208	C
	LC4512V-75FTN256C	512	3.3	7.5	Lead-free ftBGA	256	208	C
	LC4512V-35FN256C ¹	512	3.3	3.5	Lead-free fpBGA	256	208	C
	LC4512V-5FN256C ¹	512	3.3	5	Lead-free fpBGA	256	208	C
	LC4512V-75FN256C ¹	512	3.3	7.5	Lead-free fpBGA	256	208	C
	LC4512V-35TN176C	512	3.3	3.5	Lead-free TQFP	176	128	C
	LC4512V-5TN176C	512	3.3	5	Lead-free TQFP	176	128	C
	LC4512V-75TN176C	512	3.3	7.5	Lead-free TQFP	176	128	C

1. Use ftBGA package. fpBGA package devices have been discontinued via PCN#14A-07.

ispMACH 4000V (3.3V) Lead-Free Industrial Devices (Cont.)

Device	Part Number	Macrocells	Voltage	t _{PD}	Package	Pin/Ball Count	I/O	Grade
LC4256V	LC4256V-5FTN256AI	256	3.3	5	Lead-free ftBGA	256	128	I
	LC4256V-75FTN256AI	256	3.3	7.5	Lead-free ftBGA	256	128	I
	LC4256V-10FTN256AI	256	3.3	10	Lead-free ftBGA	256	128	I
	LC4256V-5FTN256BI	256	3.3	5	Lead-free ftBGA	256	160	I
	LC4256V-75FTN256BI	256	3.3	7.5	Lead-free ftBGA	256	160	I
	LC4256V-10FTN256BI	256	3.3	10	Lead-free ftBGA	256	160	I
	LC4256V-5FN256AI ¹	256	3.3	5	Lead-free fpBGA	256	128	I
	LC4256V-75FN256AI ¹	256	3.3	7.5	Lead-free fpBGA	256	128	I
	LC4256V-10FN256AI ¹	256	3.3	10	Lead-free fpBGA	256	128	I
	LC4256V-5FN256BI ¹	256	3.3	5	Lead-free fpBGA	256	160	I
	LC4256V-75FN256BI ¹	256	3.3	7.5	Lead-free fpBGA	256	160	I
	LC4256V-10FN256BI ¹	256	3.3	10	Lead-free fpBGA	256	160	I
	LC4256V-5TN176I	256	3.3	5	Lead-free TQFP	176	128	I
	LC4256V-75TN176I	256	3.3	7.5	Lead-free TQFP	176	128	I
	LC4256V-10TN176I	256	3.3	10	Lead-free TQFP	176	128	I
	LC4256V-5TN144I	256	3.3	5	Lead-free TQFP	144	96	I
	LC4256V-75TN144I	256	3.3	7.5	Lead-free TQFP	144	96	I
	LC4256V-10TN144I	256	3.3	10	Lead-free TQFP	144	96	I
	LC4256V-5TN100I	256	3.3	5	Lead-free TQFP	100	64	I
	LC4256V-75TN100I	256	3.3	7.5	Lead-free TQFP	100	64	I
	LC4256V-10TN100I	256	3.3	10	Lead-free TQFP	100	64	I
LC4384V	LC4384V-5FTN256I	384	3.3	5	Lead-free ftBGA	256	192	I
	LC4384V-75FTN256I	384	3.3	7.5	Lead-free ftBGA	256	192	I
	LC4384V-10FTN256I	384	3.3	10	Lead-free ftBGA	256	192	I
	LC4384V-5FN256I ¹	384	3.3	5	Lead-free fpBGA	256	192	I
	LC4384V-75FN256I ¹	384	3.3	7.5	Lead-free fpBGA	256	192	I
	LC4384V-10FN256I ¹	384	3.3	10	Lead-free fpBGA	256	192	I
	LC4384V-5TN176I	384	3.3	5	Lead-free TQFP	176	128	I
	LC4384V-75TN176I	384	3.3	7.5	Lead-free TQFP	176	128	I
LC4512V	LC4512V-5FTN256I	512	3.3	5	Lead-free ftBGA	256	208	I
	LC4512V-75FTN256I	512	3.3	7.5	Lead-free ftBGA	256	208	I
	LC4512V-10FTN256I	512	3.3	10	Lead-free ftBGA	256	208	I
	LC4512V-5FN256I ¹	512	3.3	5	Lead-free fpBGA	256	208	I
	LC4512V-75FN256I ¹	512	3.3	7.5	Lead-free fpBGA	256	208	I
	LC4512V-10FN256I ¹	512	3.3	10	Lead-free fpBGA	256	208	I
	LC4512V-5TN176I	512	3.3	5	Lead-free TQFP	176	128	I
	LC4512V-75TN176I	512	3.3	7.5	Lead-free TQFP	176	128	I
	LC4512V-10TN176I	512	3.3	10	Lead-free TQFP	176	128	I

1. Use ftBGA package. fpBGA package devices have been discontinued via PCN#14A-07.